

MURF1060

Rev.F Mar.-2016

/ Descriptions

TO-220FAC

Ultrafast Recovery Diode in a TO-220FAC Plastic Package.

Silicon epitaxial process to produce ultrafast recovery diode with low reverse leakage current and high reliability.

For high frequency, high voltage, high current rectifier diode, freewheeling diode



PIN 1 2 Cathode

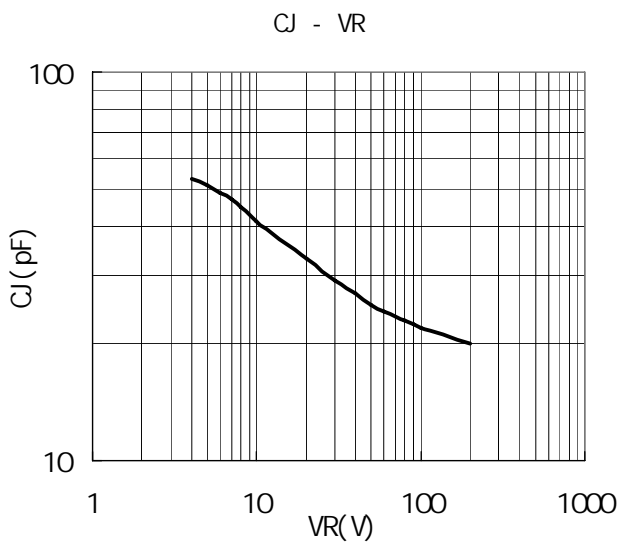
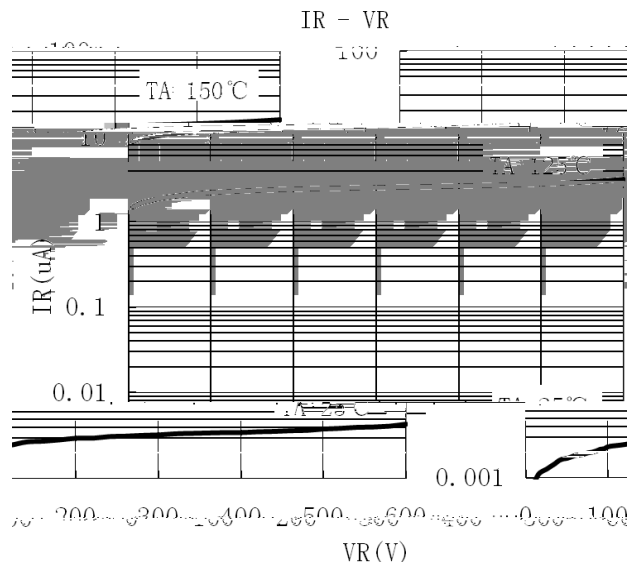
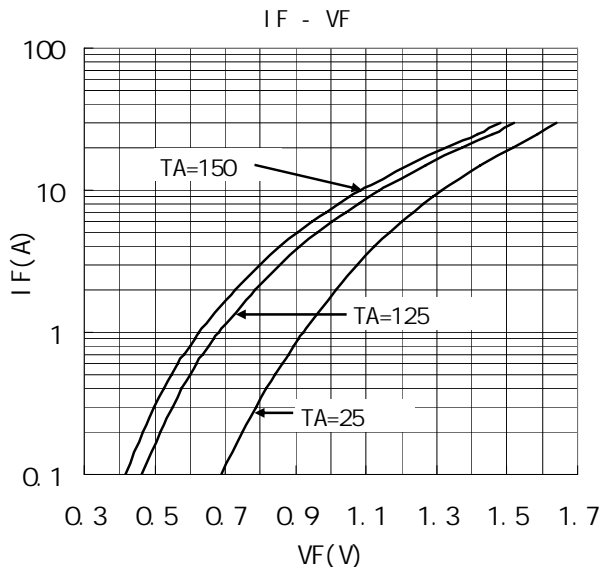
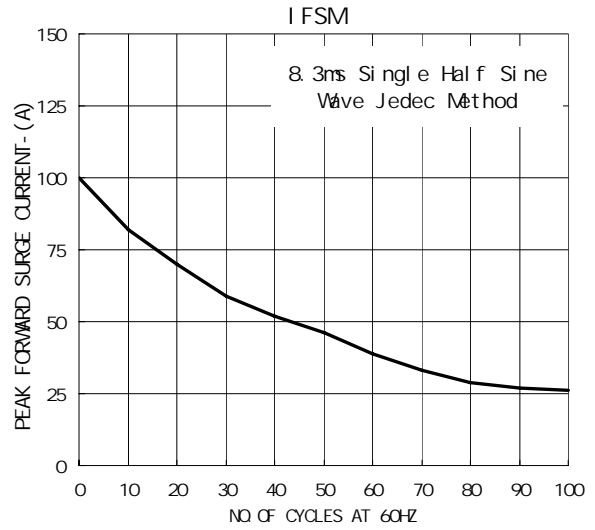
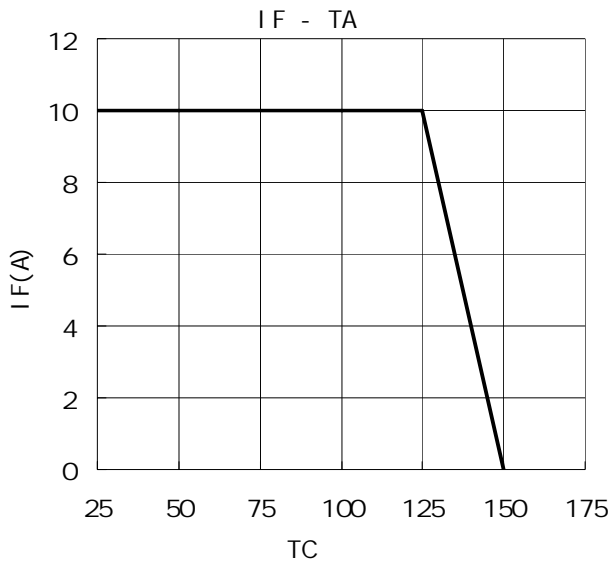
PIN 3 Anode

/ h_{FE} Classifications & Marking

See Marking Instructions

Parameter	Symbol	Rating	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	600	V
RMS Reverse Voltage	V_{RMS}	420	V
DC Blocking Voltage	V_{DC}	600	V
Forward Current	I_F	1 × 10	A
Peak forward surge current	I_{FSM}	100	A
Typical Thermal Resistance Junction to Case	R_{Jc}	4	/W

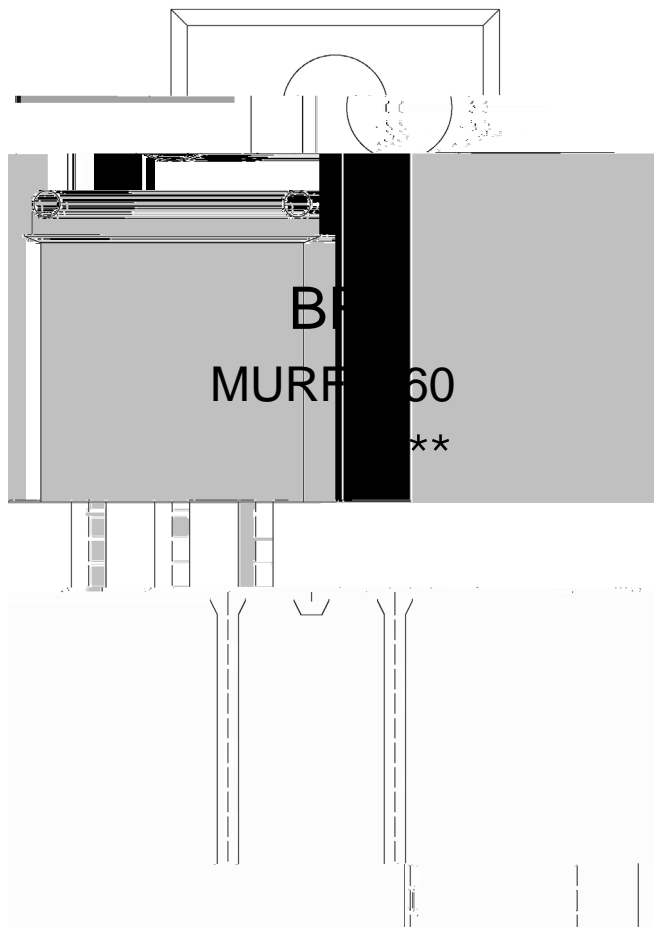
/ Electrical Characteristic Curve



/ Package Dimensions



/ Marking Instructions



BR

MURF1060

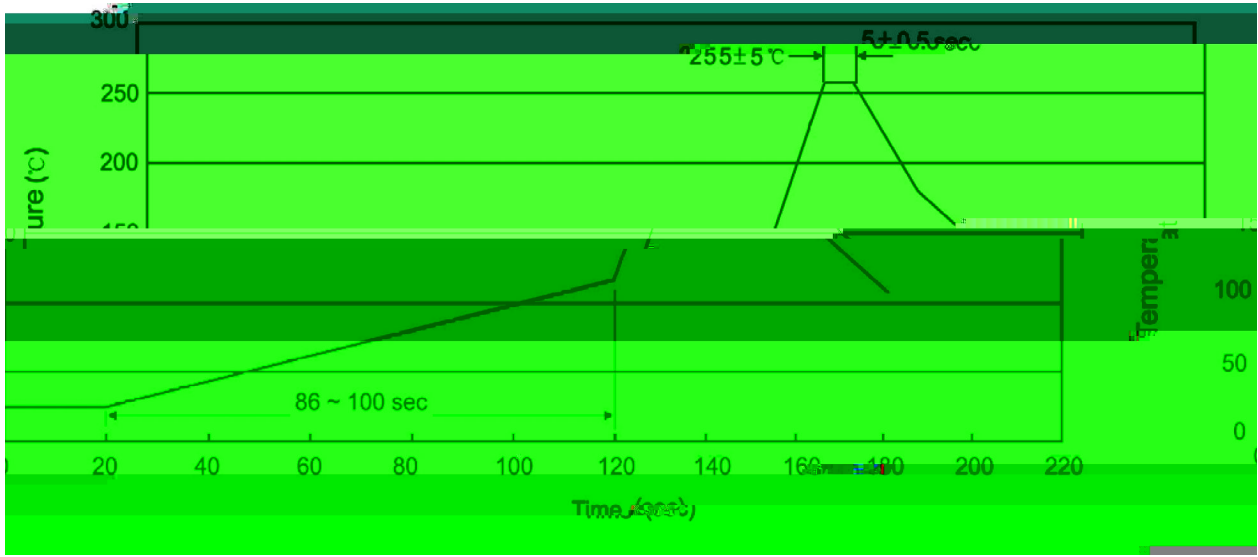
Note:

BR: Company Code

MURF1060 Product Type.

***: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note: